

PATENT ASSIGNMENT

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SUBMISSION TYPE:	NEW ASSIGNMENT										
NATURE OF CONVEYANCE:	ASSIGNMENT										
CONVEYING PARTY DATA											
<table border="1"> <thead> <tr> <th>Name</th> <th>Execution Date</th> </tr> </thead> <tbody> <tr> <td>Chizu SAITO</td> <td>07/22/2013</td> </tr> <tr> <td>Hiroyuki KATO</td> <td>07/22/2013</td> </tr> <tr> <td>Michihiro SANO</td> <td>07/22/2013</td> </tr> </tbody> </table>		Name	Execution Date	Chizu SAITO	07/22/2013	Hiroyuki KATO	07/22/2013	Michihiro SANO	07/22/2013		
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RECEIVING PARTY DATA											
<table border="1"> <tr> <td>Name:</td> <td>STANLEY ELECTRIC CO., LTD.</td> </tr> <tr> <td>Street Address:</td> <td>2-9-13, Nakameguro</td> </tr> <tr> <td>Internal Address:</td> <td>Meguro-ku</td> </tr> <tr> <td>City:</td> <td>Tokyo</td> </tr> <tr> <td>State/Country:</td> <td>JAPAN</td> </tr> </table>		Name:	STANLEY ELECTRIC CO., LTD.	Street Address:	2-9-13, Nakameguro	Internal Address:	Meguro-ku	City:	Tokyo	State/Country:	JAPAN
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PROPERTY NUMBERS Total: 1											
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CORRESPONDENCE DATA											
Fax Number:	2123195101										
<i>Correspondence will be sent via US Mail when the fax attempt is unsuccessful.</i>											
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ATTORNEY DOCKET NUMBER:	13535										
NAME OF SUBMITTER:	Amit Kulkarni										
Signature:	/ak/										

Date:	07/23/2013
	This document serves as an Oath/Declaration (37 CFR 1.63).
Total Attachments: 3 source=13535_Declaration_Assignment#page1.tif source=13535_Declaration_Assignment#page2.tif source=13535_Declaration_Assignment#page3.tif	

Combined Declaration and Assignment

Title of Invention	METHOD FOR PRODUCING P-TYPE ZnO BASED COMPOUND SEMICONDUCTOR LAYER, METHOD FOR PRODUCING ZnO BASED COMPOUND SEMICONDUCTOR ELEMENT, P-TYPE ZnO BASED COMPOUND SEMICONDUCTOR SINGLE CRYSTAL LAYER, ZnO BASED COMPOUND SEMICONDUCTOR ELEMENT, AND N-TYPE ZnO BASED COMPOUND SEMICONDUCTOR LAMINATE STRUCTURE	
As the below named inventor, I hereby declare that:		
This declaration is directed to:		
<input checked="" type="checkbox"/> The attached application, or <input type="checkbox"/> United States application or PCT international application number _____ filed on _____.		
The above-identified application was made or authorized to be made by me.		
I believe that I am the original inventor or an original joint inventor of a claimed invention in the application.		
In consideration of value received, I sell and assign to <u>STANLEY ELECTRIC CO., LTD.</u> , having a business address at <u>2-9-13, Nakameguro, Meguro-ku, Tokyo, Japan</u> , its successors, assigns or nominees, hereinafter referred to as "Assignee", my entire right, title and interest in and to said invention, and in and to all applications for patent and patents for said invention, in all countries of the world, including all divisions, reissues, continuations, substitutions and extensions thereof and all rights arising under or pursuant to any and all international agreements, treaties or laws relating to the protection of intellectual property, including rights of priority, resulting from the filing of any of said applications.		
I authorize said Assignee to file and prosecute an application or applications for patent for said invention as the applicant, and I request any official whose duty it is to issue patents, to issue any patent on said invention to said Assignee.		
I agree that on request and without further consideration, but at the expense of said Assignee, I will communicate to said Assignee or its representatives all facts known to me respecting said invention and testify in any legal proceeding, sign all lawful papers, execute all divisional, continuing, reissue, or other applications, make all rightful oaths and declarations, and generally do everything possible to aid said Assignee to obtain and enforce proper patent protection for said invention in all countries.		
I hereby acknowledge that any willful false statement made in this declaration is punishable under 18 U.S.C. 1001 by fine or imprisonment of not more than five (5) years, or both.		
LEGAL NAME OF INVENTOR		
Chizu SAITO	<i>Chizu Saito</i>	July 22, 2013
Inventor (printed name)	Signature	Date

Holtz, Holtz, Goodman & Chick PC
 220 Fifth Avenue, 16th Floor, New York, NY 10001-7708
 Tel. (212) 319-4900 Fax. (212) 319-5101

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LEGAL NAME OF INVENTOR		
Hiroyuki KATO	<i>Hiroyuki Kato</i>	July 22, 2013
Inventor (printed name)	Signature	Date

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LEGAL NAME OF INVENTOR		
Michihiro SANO	<i>Michihiro, Sano</i>	<i>July, 22, 2013</i>
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